

LP38855 1.5A Fast-Response High-Accuracy LDO Linear Regulator with Enable

General Description

.dzsc.com

The LP38855 is a high-current, fast-response regulator which can maintain output voltage regulation with an extremely low input to output voltage drop. Fabricated on a CMOS process, the device operates from two input voltages: V_{BIAS} provides power for the internal bias and control circuits, as well as drive for the gate of the N-MOS power transistor, while V_{IN} supplies power to the load. The use of an external bias rail allows the part to operate from ultra low V_{IN} voltages. Unlike bipolar regulators, the CMOS architecture consumes extremely low quiescent current at any output load current. The use of an N-MOS power transistor results in wide bandwidth, yet minimum external capacitance is required to maintain loop stability.

The fast transient response of this device makes it suitable for use in powering DSP, Microcontroller Core voltages and Switch Mode Power Supply post regulators. The LP38855 is available in TO-220 and TO-263 5-Lead packages.

Dropout Voltage: 130 mV (typical) at 1.5A load current.

Low Ground Pin Current: 14 mA (typical) at 1.5A load current.

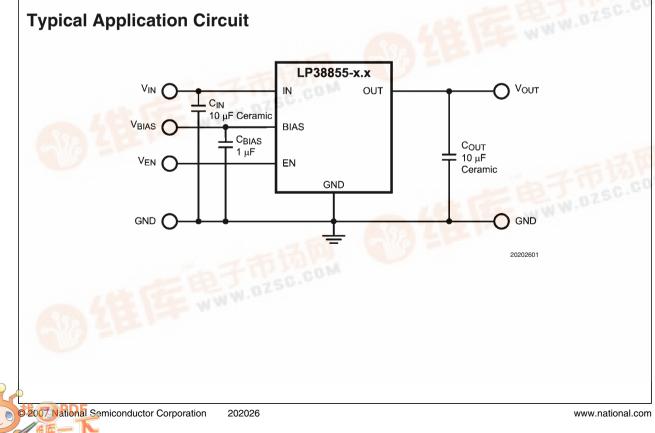
Shutdown Current: 1 μ A (typical) I_{IN(GND)} when EN pin is low. Precision Output Voltage: $\pm 1.0\%$ for T_J = 25°C and $\pm 2.0\%$ for 0°C \leq T_J \leq +125°C, across all line and load conditions

Features

- Standard V_{OUT} values of 0.8V and 1.2V
- Wide V_{BIAS} Supply operating range of 3.0V to 5.5V
- Stable with 10 μF ceramic capacitors
- Dropout voltage of 130 mV (typical) at 1.5A load current
- Precision Output Voltage across all line and load conditions:
 - $\pm 1.0\%$ for T_J = 25°C
 - $\pm 2.0\%$ for $0^{\circ}C \leq T_{J} \leq +125^{\circ}C$
 - $\pm 3.0\%$ for $-40^{\circ}C \le T_{J} \le +125^{\circ}C$
- Over-Temperature and Over-Current protection
- Available in 5 lead TO-220 and TO-263 packages
- Custom V_{OUT} values between 0.8V and 1.2V are available
- -40°C to +125°C Operating Temperature Range

Applications

- ASIC Power Supplies In: - Desktops, Notebooks, and Graphics Cards, Servers - Gaming Set Top Boxes, Printers and Copiers
- Server Core and I/O Supplies
- DSP and FPGA Power Supplies
- SMPS Post-Regulator



LP38855

| 55S-0.8 55X-0.8 55T-0.8 55S-1.2 55X-1.2 55X-1.2 55T-1.2 0.8V and 1.2V pleas | TO263-5 TO263-5 TO220-5 TO263-5 TO263-5 TO263-5 TO220-5 se contact the National Semi | TS5B TS5B T05D TS5B TS5B T05D iconductor Sales Office. | Rail of 45Tape and Reel of 500Rail of 45Rail of 45Tape and Reel of 500Rail of 45 | |
|--|---|--|--|--|
| 55T-0.8 55S-1.2 55X-1.2 55T-1.2 | TO220-5 TO263-5 TO263-5 TO220-5 | T05D TS5B TS5B T05D | Rail of 45 Rail of 45 Tape and Reel of 500 | |
| 55S-1.2 5SX-1.2 55T-1.2 | TO263-5 TO263-5 TO220-5 | TS5B TS5B T05D | Rail of 45 Tape and Reel of 500 | |
| 5SX-1.2 55T-1.2 | TO263-5 TO220-5 | TS5B T05D | Tape and Reel of 500 | |
| 55T-1.2 | TO220-5 | T05D | • | |
| | | | Rail of 45 | |
| 0.8V and 1.2V pleas | e contact the National Semi | iconductor Sales Office. | | |
| | 20202602 | BIAS 5 | For View | |
| | | | | |
| | TO220–5 and TO263 | 3–5 Packages | | |
| | | Pin Description | | |
| | ● FP3885555 5555 53, Top View | 20202602 53, Top View | | |

The regulated output voltage pin

Information section for details

The supply for the internal control and reference circuitry

The TAB is a thermal connection that is physically attached to the backside of

the die, and is used as a thermal heat-sink connection. See the Application

4

5

TAB

OUT

BIAS

TAB

Absolute Maximum Ratings (Note 1) 查询"LP38855"供应商 If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/ Distributors for availability and specifications.

| Storage Temperature Range | -65°C to +150°C |
|---|--------------------|
| Lead Temperature | |
| Soldering, 5 seconds | 260°C |
| ESD Rating | |
| Human Body Model (Note 2) | ±2 kV |
| Power Dissipation (Note 3) | Internally Limited |
| V _{IN} Supply Voltage (Survival) | -0.3V to +6.0V |
| V _{BIAS} Supply Voltage (Survival) | -0.3V to +6.0V |

V_{EN} Voltage (Survival) -0.3V to +6.0V V_{OUT} Voltage (Survival) -0.3V to +6.0V IOUT Current (Survival) Internally Limited Junction Temperature -40°C to +150°C

Operating Ratings (Note 1)

| V _{IN} Supply Voltage | $(V_{OUT} + V_{DO})$ to V_{BIAS} |
|--------------------------------------|------------------------------------|
| V _{BIAS} Supply Voltage | 3.0V to 5.5V |
| V _{EN} Enable Input Voltage | 0.0V to V _{BIAS} |
| Ι _{ουτ} | 0 mA to 1.5A |
| Junction Temperature Range (Note 3) | -40°C to +125°C |

Electrical Characteristics Unless otherwise specified: $V_{IN} = V_{OUT(NOM)} + 1V$, $V_{BIAS} = 3.0V$, $I_{OUT} = 10$ mA, $C_{IN} = 10$ $C_{OUT} = 10 \ \mu\text{F}$, $C_{BIAS} = 1 \ \mu\text{F}$, $V_{EN} = V_{BIAS}$. Limits in standard type are for $T_J = 25^{\circ}\text{C}$ only; limits in **boldface type** apply over the junction temperature (T_J) range of -40°C to +125°C. Minimum and Maximum limits are guaranteed through test, design, or statistical correlation. Typical values represent the most likely parametric norm at T_J = 25°C, and are provided for reference purposes only.

| Symbol | Parameter | Conditions | MIN | ТҮР | MAX | Units |
|--|---|---|---------------------|-----------------|---------------------|-------|
| V _{OUT} Output Voltage Tolerance | | $\begin{split} & V_{OUT(NOM)} + 1V \leq V_IN \leq V_BIAS, \\ & 3.0V \leq V_BIAS \leq 5.5V, \\ & 10 \;mA \leq I_OUT \leq 1.5A \end{split}$ | -1.0 -3.0 | 0 | +1.0 +3.0 | |
| | $\begin{split} & V_{OUT(NOM)} + 1V \leq V_IN \leq V_BIAS, \\ & 3.0V \leq V_BIAS \leq 5.5V, \\ & 10 \ mA \leq I_OUT \leq 1.5A, \\ & 0^\circC \leq T_J \leq 125^\circC \end{split}$ | -2.0 | 0 | +2.0 | % | |
| $\Delta V_{OUT} / \Delta V_{IN}$ | Line Regulation, V _{IN} (Note 4) | $V_{OUT(NOM)} + 1V \le V_{IN} \le V_{BIAS}$ | - | 0.04 | - | %/V |
| ΔV _{OUT} /ΔV _{BIAS} | Line Regulation, V _{BIAS} (Note 4) | $3.0V \le V_{BIAS} \le 5.5V$ | - | 0.10 | - | %/V |
| ΔV _{OUT} /ΔΙ _{OUT} | Output Voltage Load Regulation (Note 5) | 10 mA ≤ I _{OUT} ≤ 1.5A | - | 0.2 | - | %/A |
| V _{DO} | Dropout Voltage V _{IN} – V _{OUT} (Note 6) | I _{OUT} = 1.5A | - | 130 | 165 180 | mV |
| Ground Pin Current Drawn from I _{GND(IN)} V _{IN} Supply | | LP38855-0.8 10 mA ≤ I _{OUT} ≤ 1.5A | - | 7.0 | 8.5 9.0 | - mA |
| | LP38855-1.2 10 mA ≤ I _{OUT} ≤ 1.5A | - | 11 | 12 15 | | |
| | | $V_{EN} \le 0.5V$ | - | 1.0 | 10 300 | μA |
| | Ground Pin Current Drawn from V _{BIAS} Supply | 10 mA ≤ I _{OUT} ≤ 1.5A | - | 3.0 | 3.8 4.5 | mA |
| | | $V_{EN} \leq 0.5V$ | - | 100 | 170 200 | μA |
| UVLO | Under-Voltage Lock-Out Threshold | V _{BIAS} rising until device is functional | 2.20 2.00 | 2.45 | 2.70 2.90 | v |
| UVLO _(HYS) | Under-Voltage Lock-Out Hysteresis | V _{BIAS} falling from UVLO threshold until device is non-functional | 60 50 | 150 | 300 350 | mV |
| I _{SC} | Output Short-Circuit Current | $V_{IN} = V_{OUT(NOM)} + 1V,$ $V_{BIAS} = 3.0V, V_{OUT} = 0.0V$ | - | 4.5 | - | А |

LP38855

| Symbol | Parameter | Conditions | MIN | ТҮР | MAX | Units |
|---|---|--|---------------------|------|---------------------|-------------------|
| MABLE 366 | 55"供应商 | • | • | • | • | • |
| I _{EN} | ENABLE pin Current | $V_{\rm EN} = V_{\rm BIAS}$ | - | 0.01 | - | μA |
| | | V _{EN} = 0.0V, V _{BIAS} = 5.5V | -19 -13 | -30 | -40 -51 | |
| V _{EN(ON)} | Enable Voltage Threshold | V _{EN} rising until Output = ON | 1.00 0.90 | 1.25 | 1.50 1.55 | V |
| V _{EN(HYS)} | Enable Voltage Hysteresis | V _{EN} falling from V _{EN(ON)} until Output = OFF | 50 30 | 100 | 150 200 | mV |
| t _{OFF} | Turn-OFF Delay Time | R _{LOAD} × C _{OUT} << t _{OFF} | - | 20 | - | μs |
| t _{ON} | Turn-ON Delay Time | R _{LOAD} × C _{OUT} << t _{ON} | - | 15 | - | |
| C Paramete | ers | • | | | | |
| PSRR | Ripple Rejection for V _{IN} Input | $V_{IN} = V_{OUT} + 1V,$ f = 120 Hz | - | 80 | - | – dB |
| (V _{IN}) | Voltage | $V_{IN} = V_{OUT} + 1V,$ f = 1 kHz | - | 65 | - | |
| PSRR (V _{BIAS}) Ripple Rejection for | | $V_{BIAS} = V_{OUT} + 3V,$ f = 120 Hz | - | 58 | - | – dB |
| | Ripple Rejection for V _{BIAS} Voltage | $V_{BIAS} = V_{OUT} + 3V,$ f = 1 kHz | - | 58 | - | |
| | Output Noise Density | f = 120 Hz | - | 1 | - | µV/√H: |
| e _n | Output Noise Voltage | BW = 10 Hz – 100 kHz | - | 150 | - | μV _{RMS} |
| | | BW = 300 Hz – 300 kHz | - | 90 | - | |
| nermal Para | ameters | | | | | - |
| T_{SD} | Thermal Shutdown Junction Temperature | | - | 160 | - | °C |
| T _{SD(HYS)} | Thermal Shutdown Hysteresis | | - | 10 | - | |
| | Thermal Resistance, Junction to Ambient(Note 3) | TO220-5 | - | 60 | - | - °C/W |
| θ_{JA} | | TO263-5 | - | 60 | - | |
| Α | Thermal Resistance, Junction to | TO220-5 | - | 3 | - | |
| $\theta_{\rm JC}$ | Case(Note 3) | TO263-5 | - | 3 | - | |

Note 1: Absolute maximum ratings indicate limits beyond which damage to the component may occur. Operating ratings indicate conditions for which the device is intended to be functional, but do not guarantee specific performance limits. For guaranteed specifications, see Electrical Characteristics. Specifications do not apply when operating the device outside of its rated operating conditions.

Note 2: The Human Body Model (HBM) is a 100 pF capacitor discharged through a 1.5k resistor into each pin. Test method is per JESD22-A114. The HBM rating for device pin 1 (EN) is ±1.5 kV.

Note 3: Device power dissipation must be de-rated based on device power dissipation (T_D) , ambient temperature (T_A) , and package junction to ambient thermal resistance (θ_{JA}) . Additional heat-sinking may be required to ensure that the device junction temperature (T_J) does not exceed the maximum operating rating. See the Application Information section for details.

Note 4: Output voltage line regulation is defined as the change in output voltage from nominal value resulting from a change in input voltage.

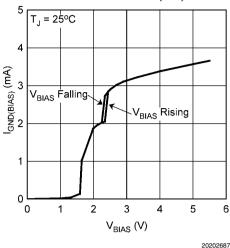
Note 5: Output voltage load regulation is defined as the change in output voltage from nominal value as the load current increases from no load to full load.

Note 6: Dropout voltage is defined the as input to output voltage differential ($V_{IN} - V_{OUT}$) where the input voltage is low enough to cause the output voltage to drop 2% from the nominal value.

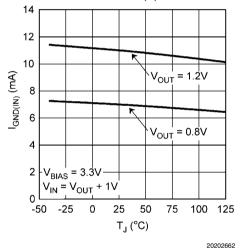
Typical Performance Characteristics Unless otherwise specified: T_J = 25°C, V_{IN} = V_{OUT(NOM)} + 1V, V_{BIAS} =查询心员我856次供应商_{OUT} = 10 µF Ceramic, C_{BIAS} = 1 µF Ceramic, V_{EN} = V_{BIAS}.

LP38855

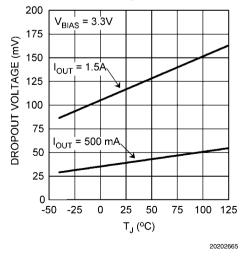




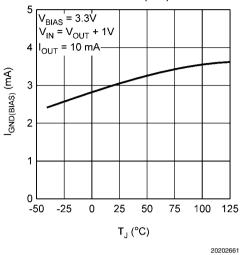
VIN Ground Pin Current (IGND(IN)) vs Temperature



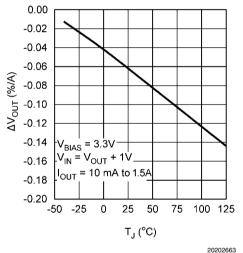
Dropout Voltage (V_{DO}) vs Temperature



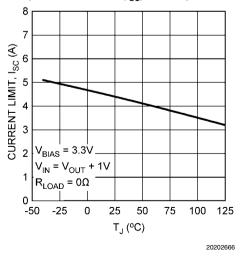
V_{BIAS} Ground Pin Current (I_{GND(BIAS)}) vs Temperature



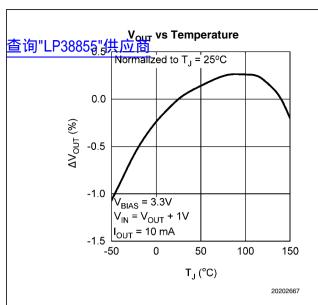
Load Regulation vs Temperature



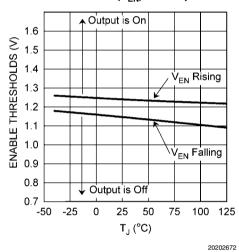
Output Current Limit (I_{SC}) vs Temperature



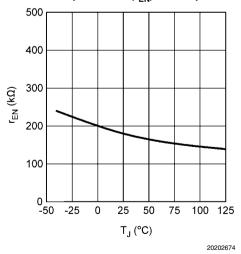




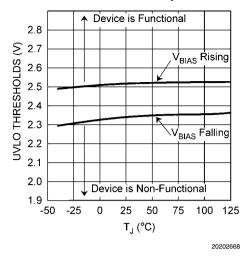
Enable Thresholds (V_{EN}) vs Temperature



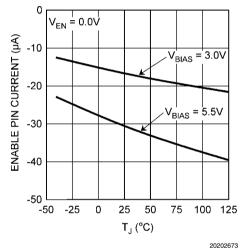
Enable Pull-Up Resistor (r_{EN}) vs Temperature



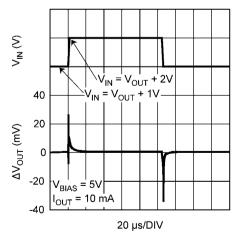
UVLO Thresholds vs Temperature



Enable Pull-Down Current (I_{EN}) vs Temperature

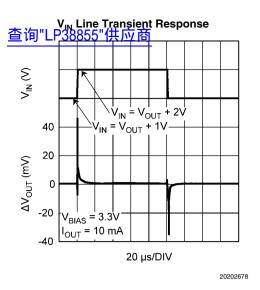


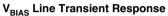
V_{IN} Line Transient Response

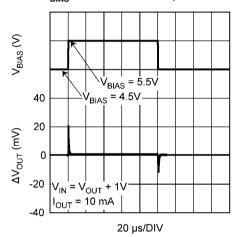


20202677



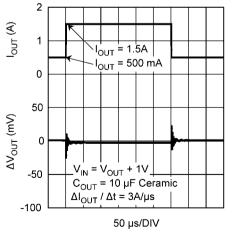






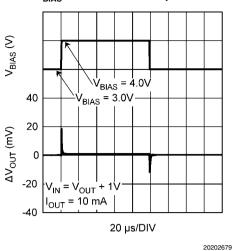
20202680

Load Transient Respose, C_{OUT} = 10 µF Ceramic

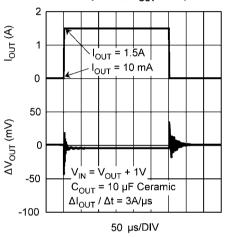


20202682

V_{BIAS} Line Transient Response

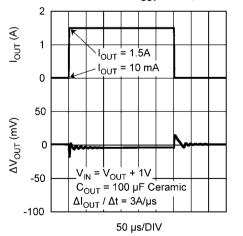


Load Transient Response, C_{OUT} = 10 µF Ceramic



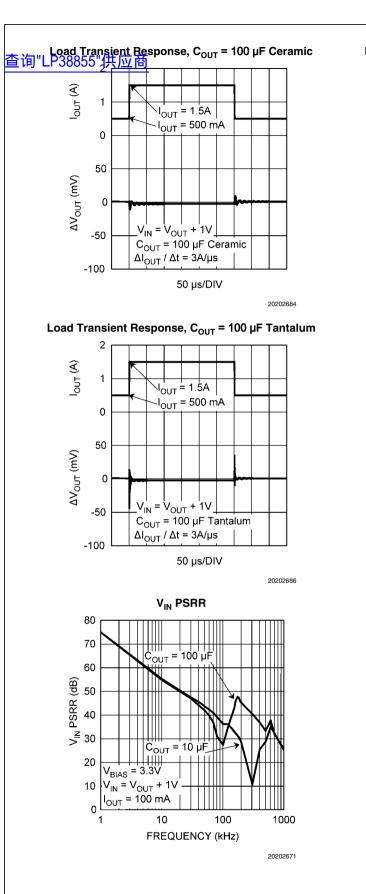
20202681

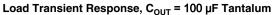
Load Transient Response, C_{OUT} = 100 µF Ceramic

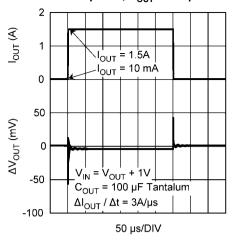


20202683

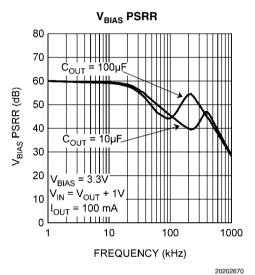




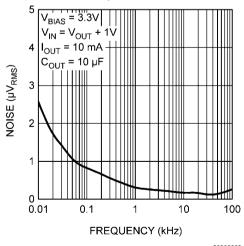




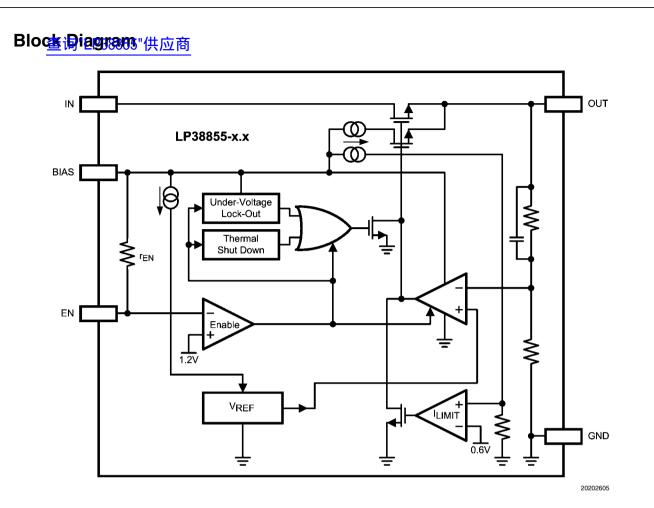
20202685



Output Noise



20202669



LP38855

Application Information 'LP38855"供应商

EXTERNAL CAPACITORS

To assure regulator stability, capacitors are required on the input, output and bias pins as shown in the Typical Application Circuit.

Output Capacitor

A minimum output capacitance of 10 µF, ceramic, is required for stability. The amount of output capacitance can be increased without limit. The output capacitor must be located less than 1 cm from the output pin of the IC and returned to the device ground pin with a clean analog ground.

Only high quality ceramic types such as X5R or X7R should be used, as the Z5U and Y5F types do not provide sufficient capacitance over temperature.

Tantalum capacitors will also provide stable operation across the entire operating temperature range. However, the effects of ESR may provide variations in the output voltage during fast load transients. Using the minimum recommended 10 µF ceramic capacitor at the output will allow unlimited capacitance, Tantalum and/or Aluminum, to be added in parallel.

Input Capacitor

The input capacitor must be at least 10 µF, but can be increased without limit. It's purpose is to provide a low source impedance for the regulator input. A ceramic capacitor, X5R or X7R, is recommended.

Tantalum capacitors may also be used at the input pin. There is no specific ESR limitation on the input capacitor (the lower, the better).

Aluminum electrolytic capacitors can be used, but are not recommended as their ESR increases very quickly at cold temperatures. They are not recommended for any application where the ambient temperature falls below 0°C.

Bias Capacitor

The capacitor on the bias pin must be at least 1 uF. It can be any good quality capacitor (ceramic is recommended).

INPUT VOLTAGE

The input voltage (V_{IN}) is the high current external voltage rail that will be regulated down to a lower voltage, which is applied to the load. The input voltage must be at least $V_{OUT} + V_{DO}$, and no higher than whatever value is used for V_{BIAS} .

BIAS VOLTAGE

The bias voltage (V_{BIAS}) is a low current external voltage rail required to bias the control circuitry and provide gate drive for the N-FET pass transistor. The bias voltage must be in the range of 3.0V to 5.5V to ensure proper operation of the device.

UNDER VOLTAGE LOCKOUT

The bias voltage is monitored by a circuit which prevents the device from functioning when the bias voltage is below the Under-Voltage Lock-Out (UVLO) threshold of approximately 2.45V.

As the bias voltage rises above the UVLO threshold the device control circuitry become active. There is approximately 150 mV of hysteresis built into the UVLO threshold to provide noise immunity.

When the bias voltage is between the UVLO threshold and the Minimum Operating Rating value of 3.0V the device will be functional, but the operating parameters will not be within the guaranteed limits.

SUPPLY SEQUENCING

There is no requirement for the order that V_{IN} or V_{BIAS} are applied or removed. However, the output voltage cannot be guaranteed until both $V_{\rm IN}$ and $V_{\rm BIAS}$ are within the range of guaranteed operating values.

If used in a dual-supply system where the regulator load is returned to a negative supply, the output pin must be diode clamped to ground. A Schottky diode is recommend for this diode clamp.

REVERSE VOLTAGE

A reverse voltage condition will exist when the voltage at the output pin is higher than the voltage at the input pin. Typically this will happen when VIN is abruptly taken low and COUT continues to hold a sufficient charge such that the input to output voltage becomes reversed.

The NMOS pass element, by design, contains no body diode. This means that, as long as the gate of the pass element is not driven, there will not be any reverse current flow through the pass element during a reverse voltage event. The gate of the pass element is not driven when V_{BIAS} is below the UVLO threshold, or the EN pin is held low.

When $\mathrm{V}_{\mathrm{BIAS}}$ is above the UVLO threshold, and the EN pin is above the $V_{EN(ON)}$ threshold, the control circuitry is active and will attempt to regulate the output voltage. Since the input voltage is less than the output voltage the control circuit will drive the gate of the pass element to the full V_{BIAS} potential when the output voltage begins to fall. In this condition, reverse current will flow from the output pin to the input pin. limited only by the $\mathrm{R}_{\mathrm{DS}(\mathrm{ON})}$ of the pass element and the output to input voltage differential. Discharging an output capacitor up to 1000 µF in this manner will not damage the device as the current will decay rapidly. However, continuous reverse current should be avoided.

ENABLE OPERATION

The Enable pin (EN) provides a mechanism to enable, or disable, the regulator output stage. The Enable pin has an internal pull-up, through a typical 180 k Ω resistor, to V_{BIAS}.

If the Enable pin is actively driven, pulling the Enable pin above the V_{EN} threshold of 1.25V (typical) will turn the regulator output on, while pulling the Enable pin below the V_{EN} threshold will turn the regulator output off. There is approximately 100 mV of hysteresis built into the Enable threshold provide noise immunity.

If the Enable function is not needed this pin should be left open, or connected directly to V_{BIAS}. If the Enable pin is left open, stray capacitance on this pin must be minimized, otherwise the output turn-on will be delayed while the stray capacitance is charged through the internal resistance (r_{EN}).

POWER DISSIPATION AND HEAT-SINKING

A heat-sink may be required depending on the maximum power dissipation and maximum ambient temperature of the application. Under all possible conditions, the junction temperature must be within the range specified under operating conditions.

The total power dissipation of the device is the sum of three different points of dissipation in the device.

The first part is the power that is dissipated in the NMOS pass element, and can be determined with the formula:

$$\mathsf{P}_{\mathsf{D}(\mathsf{PASS})} = (\mathsf{V}_{\mathsf{IN}} - \mathsf{V}_{\mathsf{OUT}}) \times \mathsf{I}_{\mathsf{OUT}} \tag{1}$$

The second part is the power that is dissipated in the bias and control 查给真理, 周98350 的社会 Financial with the formula:

$$\mathsf{P}_{\mathsf{D}(\mathsf{BIAS})} = \mathsf{V}_{\mathsf{BIAS}} \times \mathsf{I}_{\mathsf{GND}(\mathsf{BIAS})} \tag{2}$$

where $I_{GND(BIAS)}$ is the portion of the operating ground current of the device that is related to V_{BIAS} .

The third part is the power that is dissipated in portions of the output stage circuitry, and can be determined with the formula:

$$\mathsf{P}_{\mathsf{D}(\mathsf{IN})} = \mathsf{V}_{\mathsf{IN}} \times \mathsf{I}_{\mathsf{GND}(\mathsf{IN})} \tag{3}$$

where $I_{GND(IN)}$ is the portion of the operating ground current of the device that is related to V_{IN} .

The total power dissipation is then:

$$\mathsf{P}_{\mathsf{D}} = \mathsf{P}_{\mathsf{D}(\mathsf{PASS})} + \mathsf{P}_{\mathsf{D}(\mathsf{BIAS})} + \mathsf{P}_{\mathsf{D}(\mathsf{IN})} \tag{4}$$

The maximum allowable junction temperature rise (ΔT_{J}) depends on the maximum anticipated ambient temperature ($T_{A}_{(MAX)}$) for the application, and the maximum allowable operating junction temperature ($T_{J(MAX)}$):

$$\Delta I_{J} = I_{J(MAX)} - I_{A(MAX)}$$
(5)

The maximum allowable value for junction to ambient Thermal Resistance, $\theta_{i,la}$, can be calculated using the formula:

$$\theta_{JA} \leq \frac{\Delta T_{J}}{P_{D}}$$
(6)

Heat-Sinking The TO-220 Package

The TO-220 package has a θ_{JA} rating of 60°C/W, and a θ_{JC} rating of 3°C/W. These ratings are for the package only, no additional heat-sinking, and with no airflow.

The thermal resistance of a TO-220 package can be reduced by attaching it to a heat-sink or a copper plane on a PC board. If a copper plane is to be used, the values of θ_{JA} will be same as shown in next section for TO-263 package.

The heat-sink to be used in the application should have a heat-sink to ambient thermal resistance, θ_{HA} :

$$\theta_{HA} \le \theta_{JA} - (\theta_{CH} + \theta_{JC}) \tag{7}$$

where θ_{JA} is the required total thermal resistance from the junction to the ambient air, θ_{CH} is the thermal resistance from the case to the surface of the heat sink, and θ_{JC} is the thermal resistance from the junction to the surface of the case.

For this equation, θ_{JC} is about 3°C/W for a TO-220 package. The value for θ_{CH} depends on method of attachment, insulator, etc. θ_{CH} varies between 1.5°C/W to 2.5°C/W. Consult the heat-sink manufacturer datasheet for details and recommendations.

Heat-Sinking The TO-263 Package

The TO-263 package has a θ_{JA} rating of 60°C/W, and a θ_{JC} rating of 3°C/W. These ratings are for the package only, no additional heat-sinking, and with no airflow.

The TO-263 package uses the copper plane on the PCB as a heat-sink. The tab of this package is soldered to the copper plane for heat-sinking. The graph below shows a curve for the θ_{JA} of TO-263 package for different copper area sizes, using a typical PCB with 1 ounce copper and no solder mask over the copper area for heat-sinking.

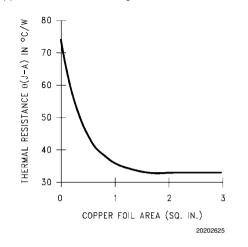


FIGURE 1. θ_{JA} vs Copper (1 Ounce) Area for the TO-263 package

As shown in *Figure 1*, increasing the copper area beyond 1 square inch produces very little improvement. The minimum value for θ_{JA} for the TO-263 package mounted to a PCB is 32°C/W.

Figure 2 shows the maximum allowable power dissipation for TO-263 packages for different ambient temperatures, assuming θ_{JA} is 35°C/W and the maximum junction temperature is 125°C.

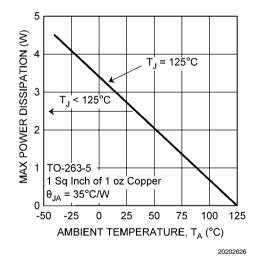
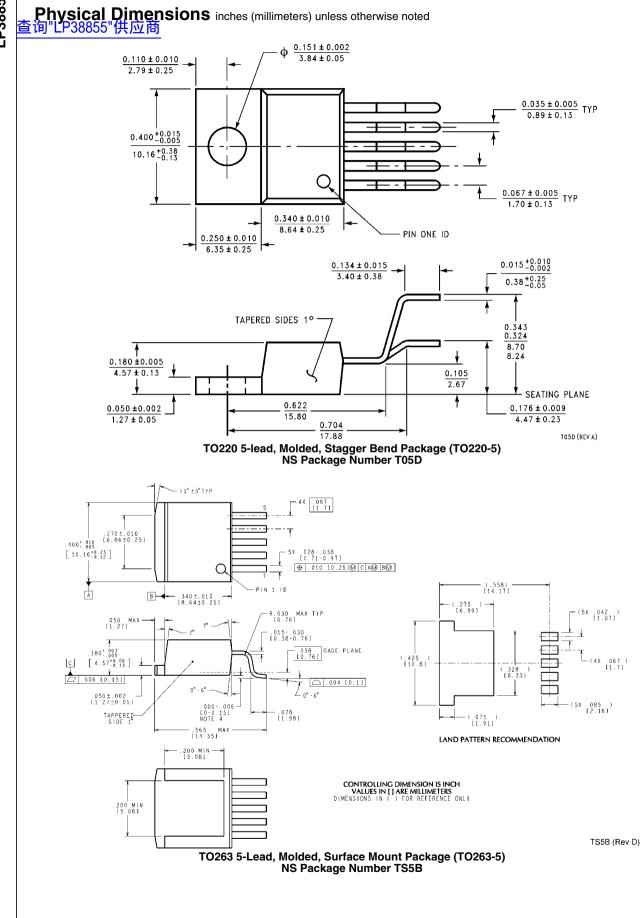


FIGURE 2. Maximum Power Dissipation vs Ambient Temperature for TO-263 package



查询"LP38855"供应商

Notes

LP38855

查询"LP38855"供应商

Notes

THE CONTENTS OF THIS DOCUMENT ARE PROVIDED IN CONNECTION WITH NATIONAL SEMICONDUCTOR CORPORATION ("NATIONAL") PRODUCTS. NATIONAL MAKES NO REPRESENTATIONS OR WARRANTIES WITH RESPECT TO THE ACCURACY OR COMPLETENESS OF THE CONTENTS OF THIS PUBLICATION AND RESERVES THE RIGHT TO MAKE CHANGES TO SPECIFICATIONS AND PRODUCT DESCRIPTIONS AT ANY TIME WITHOUT NOTICE. NO LICENSE, WHETHER EXPRESS, IMPLIED, ARISING BY ESTOPPEL OR OTHERWISE, TO ANY INTELLECTUAL PROPERTY RIGHTS IS GRANTED BY THIS DOCUMENT.

TESTING AND OTHER QUALITY CONTROLS ARE USED TO THE EXTENT NATIONAL DEEMS NECESSARY TO SUPPORT NATIONAL'S PRODUCT WARRANTY. EXCEPT WHERE MANDATED BY GOVERNMENT REQUIREMENTS, TESTING OF ALL PARAMETERS OF EACH PRODUCT IS NOT NECESSARILY PERFORMED. NATIONAL ASSUMES NO LIABILITY FOR APPLICATIONS ASSISTANCE OR BUYER PRODUCT DESIGN. BUYERS ARE RESPONSIBLE FOR THEIR PRODUCTS AND APPLICATIONS USING NATIONAL COMPONENTS. PRIOR TO USING OR DISTRIBUTING ANY PRODUCTS THAT INCLUDE NATIONAL COMPONENTS, BUYERS SHOULD PROVIDE ADEQUATE DESIGN, TESTING AND OPERATING SAFEGUARDS.

EXCEPT AS PROVIDED IN NATIONAL'S TERMS AND CONDITIONS OF SALE FOR SUCH PRODUCTS, NATIONAL ASSUMES NO LIABILITY WHATSOEVER, AND NATIONAL DISCLAIMS ANY EXPRESS OR IMPLIED WARRANTY RELATING TO THE SALE AND/OR USE OF NATIONAL PRODUCTS INCLUDING LIABILITY OR WARRANTIES RELATING TO FITNESS FOR A PARTICULAR PURPOSE, MERCHANTABILITY, OR INFRINGEMENT OF ANY PATENT, COPYRIGHT OR OTHER INTELLECTUAL PROPERTY RIGHT.

LIFE SUPPORT POLICY

NATIONAL'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS PRIOR WRITTEN APPROVAL OF THE CHIEF EXECUTIVE OFFICER AND GENERAL COUNSEL OF NATIONAL SEMICONDUCTOR CORPORATION. As used herein:

Life support devices or systems are devices which (a) are intended for surgical implant into the body, or (b) support or sustain life and whose failure to perform when properly used in accordance with instructions for use provided in the labeling can be reasonably expected to result in a significant injury to the user. A critical component is any component in a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system or to affect its safety or effectiveness.

National Semiconductor and the National Semiconductor logo are registered trademarks of National Semiconductor Corporation. All other brand or product names may be trademarks or registered trademarks of their respective holders.

Copyright© 2007 National Semiconductor Corporation

For the most current product information visit us at www.national.com



National Semiconductor Americas Customer Support Center Email: new.feedback@nsc.com Tel: 1-800-272-9959 National Semiconductor Europe Customer Support Center Fax: +49 (0) 180-530-85-86 Email: europe.support@nsc.com Deutsch Tel: +49 (0) 69 9508 6208 English Tel: +49 (0) 870 24 0 2171 Français Tel: +33 (0) 1 41 91 8790 National Semiconductor Asia Pacific Customer Support Center Email: ap.support@nsc.com National Semiconductor Japan Customer Support Center Fax: 81-3-5639-7507 Email: jpn.feedback@nsc.com Tel: 81-3-5639-7560